

Pb Free Plating Product

## BYV26A thru BYV26G



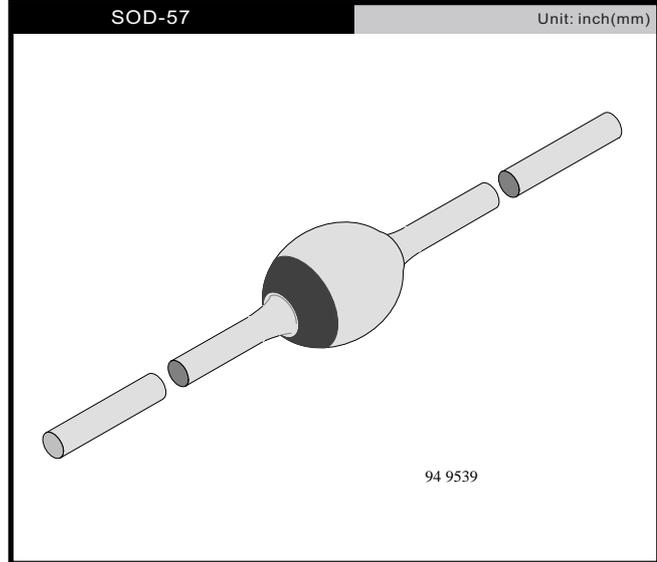
1.0 AMP.ULTRA FAST RECOVERY RECTIFIERS

## Features

- Glass passivated junction
- Hermetically sealed package
- Very low switching losses
- Low reverse current
- High reverse voltage

## Applications

Switched mode power supplies  
High-frequency inverter circuits



## Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.  
Single phase, half wave, 60 Hz, resistive or inductive load.  
For capacitive load, derate current by 20%

| Type Number  | Symbol          | BYV 26A | BYV 26B | BYV 26C | BYV 26D     | BYV 26E | BYV 26G | Units                     |
|--|-----------------|---------|---------|---------|-------------|---------|---------|---------------------------|
| Maximum Recurrent Peak Reverse Voltage   | $V_{RRM}$       | 200V    | 400V    | 600V    | 800V        | 1000V   | 1400V   | V                         |
| Maximum DC Blocking Voltage  | $V_{DC}$        | 300V    | 500V    | 700V    | 900V        | 1100V   | 1500V   | V                         |
| Maximum Average Forward Rectified Current .375 (9.5mm) Lead Length @ $T_A = 55^\circ\text{C}$              | $I_{(AV)}$      | 1.0     |         |         |             |         |         | A                         |
| Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method )        | $I_{FSM}$       | 30      |         |         |             |         |         | A                         |
| Maximum Reverse Recovery Time (Note 1)   | $T_{rr}$        | 30      |         |         | 75          |         |         | nS                        |
| Maximum DC Reverse Current @ $T_A=25^\circ\text{C}$ at Rated DC Blocking Voltage @ $T_A=150^\circ\text{C}$ | $I_R$           |         |         |         | 5.0<br>100  |         |         | uA<br>uA                  |
| Maximum Instantaneous Forward Voltage @ 1.0A @ $T_A=25^\circ\text{C}$ @ 1.0A @ $T_A=175^\circ\text{C}$     | $V_F$           |         |         |         | 2.5<br>1.3  |         |         | V                         |
| Maximum Reverse recovery Current Slope $di/dt$ @ $I_F=1A$ , $V_R=30V$ , $df/dt = 1A / \mu\text{S}$         | $dv/dt$         |         |         |         | 7           |         |         | A/ $\mu\text{S}$          |
| Typical Junction Capacitance ( Note 2 )  | $C_j$           |         |         |         | 45          |         |         | pF                        |
| Typical Thermal Resistance (Note 3)  | $R_{\theta JA}$ |         |         |         | 40          |         |         | $^\circ\text{C}/\text{W}$ |
| Operating Temperature Range  | $T_J$           |         |         |         | -55 to +175 |         |         | $^\circ\text{C}$          |
| Storage Temperature Range  | $T_{STG}$       |         |         |         | -55 to +175 |         |         | $^\circ\text{C}$          |

Notes: 1. Reverse Recovery Test Conditions:  $I_F=0.5A$ ,  $I_R=1.0A$ ,  $I_{RR}=0.25A$   
2. Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.  
3. Mount on Cu-Pad Size 5mm x 5mm on PCB.

**Characteristics** ( $T_j = 25^\circ\text{C}$  unless otherwise specified)

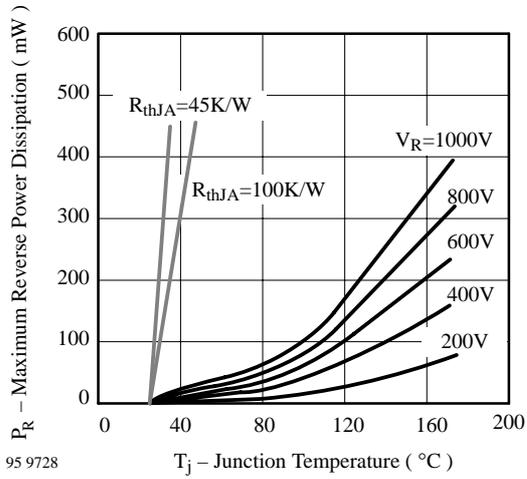


Figure 1. Max. Reverse Power Dissipation vs. Junction Temperature

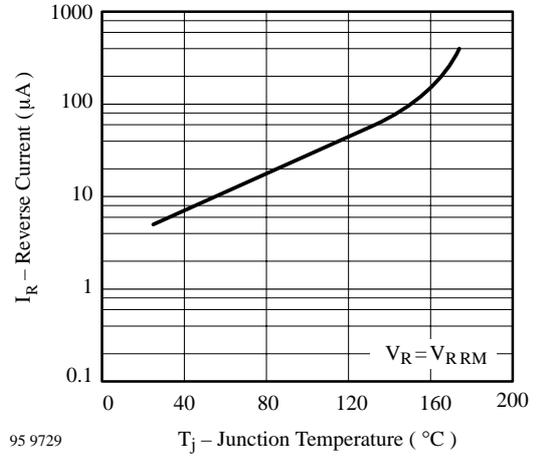


Figure 2. Max. Reverse Current vs. Junction Temperature

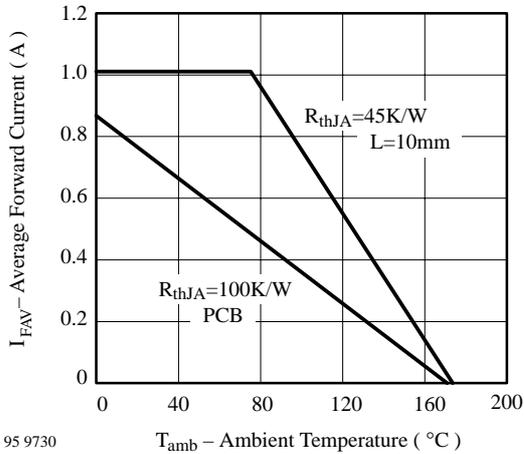


Figure 3. Max. Average Forward Current vs. Ambient Temperature

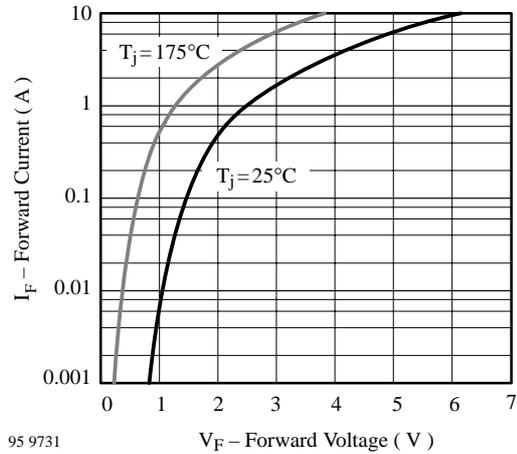


Figure 4. Max. Forward Current vs. Forward Voltage